Power Amplifier, 3 W
12.7 - 13.3 GHz

Features
- 23 dB Small Signal Gain
- 42 dBm Third Order Intercept Point (OIP3)
- >2.5 W Output P1dB
- Integrated Power Detector
- Bias 1200 mA @ 6 V
- Lead-Free 5 mm 24-lead QFN Package
- RoHS* Compliant and 260°C Reflow Compatible

Description
The MAAP-010516 is a packaged linear power amplifier that operates from 12.7 - 13.3 GHz. The device provides 23 dB gain and 42 dBm Output Third Order Intercept Point (OIP3) with 34 dBm output P1dB.

The packaged amplifier comes in an industry standard, fully molded 5 mm QFN package and is comprised of a three stage power amplifier with an integrated, temperature compensated on-chip power detector. The device includes on-chip ESD protection structures and DC by-pass capacitors to ease the implementation and volume assembly of the packaged part.

The device is specifically designed for use in 13 GHz point-to-point radios for cellular backhaul applications.

Ordering Information

<table>
<thead>
<tr>
<th>Part Number</th>
<th>Package</th>
</tr>
</thead>
<tbody>
<tr>
<td>MAAP-010516-000000</td>
<td>bulk quantity</td>
</tr>
<tr>
<td>MAAP-010516-TR0500</td>
<td>500 piece reel</td>
</tr>
<tr>
<td>MAAP-010516-001SMB</td>
<td>evaluation module</td>
</tr>
</tbody>
</table>

1. Reference Application Note M513 for reel size information.

Electrical Specifications:
Freq. = 12.7 - 13.3 GHz, \( I_{DQ} = 1200 \text{ mA} \), \( V_{DET} \) Bias = 5 V, \( V_D = 6 \text{ V} \), \( T_A = +25^\circ \text{C} \)

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Units</th>
<th>Min.</th>
<th>Typ.</th>
<th>Max.</th>
</tr>
</thead>
<tbody>
<tr>
<td>Small Signal Gain</td>
<td>dB</td>
<td>20.5</td>
<td>23.0</td>
<td>—</td>
</tr>
<tr>
<td>Input Return Loss</td>
<td>dB</td>
<td>—</td>
<td>15</td>
<td>—</td>
</tr>
<tr>
<td>Output Return Loss</td>
<td>dB</td>
<td>—</td>
<td>12</td>
<td>—</td>
</tr>
<tr>
<td>Noise Figure</td>
<td>dB</td>
<td>—</td>
<td>7</td>
<td>—</td>
</tr>
<tr>
<td>( P_{1dB} )</td>
<td>dBm</td>
<td>—</td>
<td>34.0</td>
<td>—</td>
</tr>
<tr>
<td>( P_{SAT} )</td>
<td>dBm</td>
<td>34.0</td>
<td>34.5</td>
<td>—</td>
</tr>
<tr>
<td>Output IP3, 20 dBm SCL</td>
<td>dBm</td>
<td>39.5</td>
<td>42.0</td>
<td>—</td>
</tr>
</tbody>
</table>

4. It is recommended to use active bias on gate voltages to keep the drain currents constant in order to maintain the best performance over temperature.
5. Adjust \( V_{G1}, V_{G2} \) and \( V_{G3} \) between -1.2 and -0.1 V to achieve specified \( I_{DQ} \) \( (I_{DQ}=I_{D1}+I_{D2}+I_{D3}) \). \( V_{G1}, V_{G2} \) and \( V_{G3} \) should be the same voltage.
6. See page 3 for schematic on how to connect \( V_{DET} \) and \( V_{REF} \) pins.

Maximum Operating Ratings:

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Absolute Maximum</th>
</tr>
</thead>
<tbody>
<tr>
<td>Input Power</td>
<td>18 dBm</td>
</tr>
<tr>
<td>Drain Supply Voltage</td>
<td>7 V</td>
</tr>
<tr>
<td>Junction Temperature</td>
<td>+160°C</td>
</tr>
<tr>
<td>Operating Temperature</td>
<td>-40°C to +85°C</td>
</tr>
<tr>
<td>Storage Temperature</td>
<td>-65°C to +150°C</td>
</tr>
</tbody>
</table>

7. Exceeding any one or combination of these limits may cause permanent damage to this device.
8. MACOM does not recommend sustained operation near these survivability limits.
9. Operating at nominal conditions with \( T_J \leq 160^\circ \text{C} \) will ensure MTTF > 1 \times 10^6 hours.
10. Junction Temperature \( (T_J) = T_C + \Theta_{JC} \ast ((V \ast I) - (P_{OUT} - P_{IN})) \)
    Typical thermal resistance \( \Theta_{JC} = 7.9^\circ \text{C/W} \)
    a) For \( T_C = +25^\circ \text{C} \),
       \( T_J = 91^\circ \text{C} @ 6 \text{ V}, 1.85 \text{ A}, P_{OUT} = 34.5 \text{ dBm}, P_{IN} = 14 \text{ dBm} \)
    b) For \( T_C = +85^\circ \text{C} \),
       \( T_J = 146^\circ \text{C} @ 6 \text{ V}, 1.75 \text{ A}, P_{OUT} = 34.5 \text{ dBm}, P_{IN} = 14 \text{ dBm} \)

Absolute Maximum Ratings:

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Absolute Maximum</th>
</tr>
</thead>
<tbody>
<tr>
<td>Supply Gate Voltage</td>
<td>-3 V</td>
</tr>
<tr>
<td>Supply Current</td>
<td>2200 mA</td>
</tr>
<tr>
<td>Drain to Gate Voltage</td>
<td>10 V</td>
</tr>
<tr>
<td>Continuous Power Dissipation @ +85°C</td>
<td>11.3 W</td>
</tr>
<tr>
<td>Junction Temperature</td>
<td>+175°C</td>
</tr>
</tbody>
</table>

11. Channel temperature directly affects a device’s MTTF. Channel temperature should be kept as low as possible to maximize lifetime.
12. For saturated performance it is recommended that the sum of \( (2^\ast V_{DD} + \text{abs}(V_{DD})) < 17 \text{ V} \).
Recommended PCB Layout

Schematic

Parts List

<table>
<thead>
<tr>
<th>Component</th>
<th>Value</th>
<th>Package</th>
</tr>
</thead>
<tbody>
<tr>
<td>C1,C2,C3,C14, C15,C16,C17</td>
<td>2.2 µF</td>
<td>0603</td>
</tr>
<tr>
<td>C4,C5,C6,C7,C8, C9,C10,C11,C13</td>
<td>1000 pF</td>
<td>0402</td>
</tr>
<tr>
<td>R1</td>
<td>100 KΩ</td>
<td>0402</td>
</tr>
<tr>
<td>R2</td>
<td>91 KΩ</td>
<td>0402</td>
</tr>
</tbody>
</table>

Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these Class 1A devices.
Power Amplifier, 3 W
12.7 - 13.3 GHz

Typical Performance Curves

Gain

Noise Figure @ 25°C

Input Return Loss

Output Return Loss

P1dB

PSAT

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Typical Performance Curves

Output IP3 @ +25°C

Output IP3 @ -40°C

Output IP3 @ +85°C

Output Power (dBm)

Frequency (GHz)

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Power Amplifier, 3 W
12.7 - 13.3 GHz

Typical Performance Curves

**Power Data @ 12.7 GHz, +25°C**

**Power Data @ 12.7 GHz, -40°C**

**Power Data @ 13.0 GHz, +25°C**

**Power Data @ 13.0 GHz, -40°C**

**Power Data @ 13.3 GHz, +25°C**

**Power Data @ 13.3 GHz, -40°C**
Typical Performance Curves

**Power Data @ 12.7 GHz, +85°C**

- Output Power
- Gain
- Drain Current

**Detected Voltage ($V_{REF}$ - $V_{DET}$) @ +25°C**

**Power Data @ 13.0 GHz, +85°C**

- Output Power
- Gain
- Drain Current

**Power Data @ 13.3 GHz, +85°C**

- Output Power
- Gain
- Drain Current
**Power Amplifier, 3 W**

12.7 - 13.3 GHz

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**Lead-Free 5mm 24-lead PQFN**

(All Dimensions are in millimeters)

† Reference Application Note S2083 for lead-free solder reflow recommendations.

Meets JEDEC moisture sensitivity level 1 requirements.

Plating is matte tin over Copper.